MOS FET Relays

G3VM-S5

Expanded Range of Analog-Switching MOS FET Relays in 200-V Load Voltage Series.

- Ideal replacement for the dial-pulse relay or hook relay of each modem or facsimile machine.
- Ideal for application to the line interface blocks of PBX and telephone exchange systems.
- Can be applied to hybrid IC circuits and card-type modems conforming to PCMCIA standards.
- Peak load voltage of 200 V.
- Approved standards: UL1577 (File No. E80555)



- PBX subscriber interfaces
- Multi-functional telephones
- Card-type modems and fax modems
- Built-in modems in personal computers
- Measurement devices



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Note: The actual product is marked differently from the image

shown here.

■List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	Surface-mounting	200 VAC	G3VM-S5	100	
	terminals		G3VM-S5(TR)		2,500

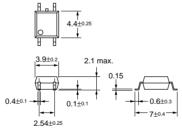
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

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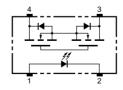
Note: The actual product is marked differently from the image shown here



Weight: 0.1 g

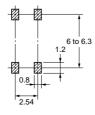
■ Terminal Arrangement/Internal Connections (Top View)

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■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

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Note:

■ Absolute Maximum Ratings (Ta = 25°C)

ltem		Symbol Rating		Unit	Measurement Conditions		
Input	Input LED forward current		50	mA			
	Repetitive peak LED forward current	I _{FP}	1	А	100 μs pulses, 100 pps		
	LED forward current reduction rate	Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C		
	LED reverse voltage	V_R	5	٧			
	Connection temperature	Tj	125	°C			
Output	Output dielectric strength	V_{OFF}	200	٧			
	Continuous load current	Io	150	mA			
	ON current reduction rate	Δ I _{ON} /°C	-1.5	mA/°C	Ta ≥ 25°C		
	Connection temperature	Tj	125	°C			
	c strength between input and See note 1.)	V _{I-O}	1,500	Vrms	AC for 1 min		
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation		
Storage temperature		T _{stg}	-55 to +100	°C	With no icing or condensation		
Soldering temperature (10 s)			260	°C	10 s		

1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

Note:

■ Electrical Characteristics (Ta = 25°C)

ltem		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions	
Input	LED forward voltage	V _F	1.0	1.15	1.3	V	I _F = 10 mA	
	Reverse current	I _R			10	μΑ	V _R = 5 V	
	Capacity between terminals	C _T		30		pF	V = 0, f = 1 MHz	
	Trigger LED forward current	I _{FT}		1	3	mA	I _O = 150 mA	
Output	Maximum resistance with output ON	R _{ON}		5	8	Ω	I _F = 5 mA, I _O = 500 mA	
	Current leakage when the relay is open	I _{LEAK}			1.0	μА	V _{OFF} = 200 V	
Capacity between I/O terminals		C _{I-O}		0.8		pF	f = 1 MHz, Vs = 0 V	
Insulation resistance		R _{I-O}	1,000			ΜΩ	V_{I-O} = 500 VDC, RoH \leq 60%	
Turn-ON time		tON		0.6	1.5	ms	I_F = 5 mA, R_L = 200 Ω , V_{DD} = 20 V (See note 2.)	
Turn-OFF time		tOFF		0.1	1.0	ms		

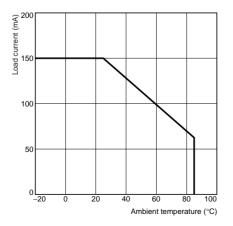
■Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V_{DD}		150	200	V
Operating LED forward current	I _F	5	7.5	25	mA
Continuous load current	Io			120	mA
Operating temperature	T _a	- 20		65	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-S5



■ Safety Precautions

Refer to page 6 for precautions common to all G3VM models.